

INA199 26-V, Bidirectional, Zero-Drift, Low- or High-Side, Voltage-Output, Current-Shunt Monitor

1 Features

- Wide Common-Mode Range: -0.3 V to 26 V
- Offset Voltage: $\pm 150\text{ }\mu\text{V}$ (Maximum)
(Enables Shunt Drops of 10-mV Full-Scale)
- Accuracy:
 - Gain Error (Maximum Over Temperature):
 - $\pm 1\%$ (C Version)
 - $\pm 1.5\%$ (A and B Versions)
 - $0.5\text{-}\mu\text{V}/^\circ\text{C}$ Offset Drift (Maximum)
 - $10\text{-ppm}/^\circ\text{C}$ Gain Drift (Maximum)
- Choice of Gains:
 - INA199x1: 50 V/V
 - INA199x2: 100 V/V
 - INA199x3: 200 V/V
- Quiescent Current: $100\text{ }\mu\text{A}$ (Maximum)
- Packages: 6-Pin SC70, 10-Pin UQFN

2 Applications

- Notebook Computers
- Cell Phones
- Qi-Compliant Wireless Charging Transmitters
- Telecom Equipment
- Power Management
- Battery Chargers

3 Description

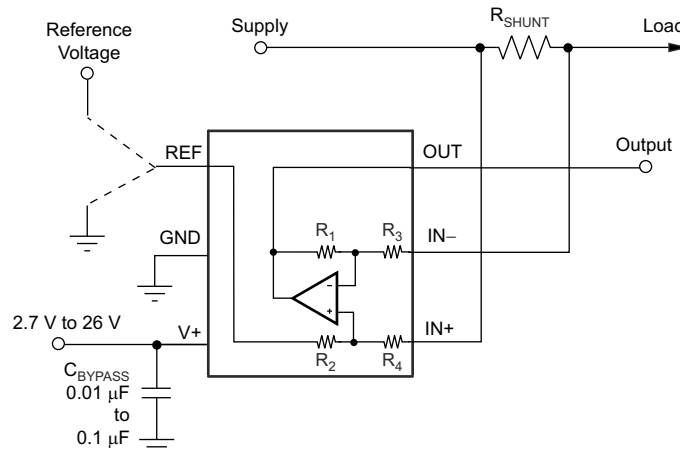
The INA199 series of voltage-output, current-shunt monitors (also called current-sense amplifiers) are commonly used for overcurrent protection, precision-current measurement for system optimization, or in closed-loop feedback circuits. This series of devices can sense drops across shunt resistors at common-mode voltages from -0.3 V to 26 V , independent of the supply voltage. Three fixed gains are available: 50 V/V , 100 V/V , and 200 V/V . The low offset of the zero-drift architecture enables current sensing with maximum drops across the shunt as low as 10-mV full-scale.

These devices operate from a single 2.7-V to 26-V power supply, drawing a maximum of $100\text{ }\mu\text{A}$ of supply current. All versions are specified from -40°C to 125°C , and offered in both SC70-6 and thin UQFN-10 packages.

Device Information

PART NUMBER	PACKAGE ⁽¹⁾	BODY SIZE (NOM)
INA199	SC70 (6)	$2.00\text{ mm} \times 1.25\text{ mm}$
	UQFN (10)	$1.80\text{ mm} \times 1.40\text{ mm}$

(1) For all available packages, see the orderable addendum at the end of the data sheet.



Simplified Schematic



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

Table of Contents

1 Features	1	8 Application and Implementation	18
2 Applications	1	8.1 Application Information.....	18
3 Description	1	8.2 Typical Applications.....	18
4 Device Comparison Table	3	9 Power Supply Recommendations	21
5 Pin Configuration and Functions	3	10 Layout	21
6 Specifications	4	10.1 Layout Guidelines.....	21
6.1 Absolute Maximum Ratings.....	4	10.2 Layout Example.....	21
6.2 ESD Ratings.....	4	11 Device and Documentation Support	22
6.3 Recommended Operating Conditions.....	5	11.1 Documentation Support.....	22
6.4 Thermal Information.....	5	11.2 Receiving Notification of Documentation Updates..	22
6.5 Electrical Characteristics.....	6	11.3 Support Resources.....	22
6.6 Typical Characteristics.....	7	11.4 Trademarks.....	22
7 Detailed Description	11	11.5 Electrostatic Discharge Caution.....	22
7.1 Overview.....	11	11.6 Glossary.....	22
7.2 Functional Block Diagram.....	11	12 Revision History	23
7.3 Feature Description.....	12	13 Mechanical, Packaging, and Orderable	
7.4 Device Functional Modes.....	13	Information	24

4 Device Comparison Table

PRODUCT	GAIN	R ₃ AND R ₄	R ₁ AND R ₂
INA199x1	50	20 kΩ	1 MΩ
INA199x2	100	10 kΩ	1 MΩ
INA199x3	200	5 kΩ	1 MΩ

5 Pin Configuration and Functions

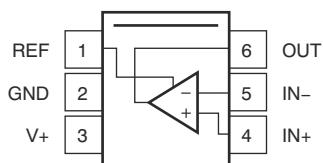


Figure 5-1. DCK Package 6-Pin SC70 Top View

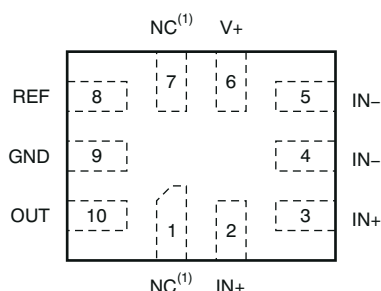


Figure 5-2. RSW Package 10-Pin UQFN Top View

A. NC⁽¹⁾ denotes no internal connection. These pins can be left floating or connected to any voltage between GND and V+.

Table 5-1. Pin Functions

NAME	PIN		I/O	DESCRIPTION
	SC70	UQFN		
GND	2	9	Analog	Ground
IN–	5	4, 5	Analog input	Connect to load side of shunt resistor.
IN+	4	2, 3	Analog input	Connect to supply side of shunt resistor.
NC	—	1, 7	—	Not internally connected. Leave floating or connect to ground.
OUT	6	10	Analog output	Output voltage
REF	1	8	Analog input	Reference voltage, 0 V to V+
V+	3	6	Analog	Power supply, 2.7 V to 26 V

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Supply voltage			26	V
Analog inputs, V_{IN+} , V_{IN-} ⁽²⁾	Differential (V_{IN+}) – (V_{IN-})	–26	26	V
	Common-mode ⁽³⁾ , INA199Ax	GND – 0.3	26	
	Common-mode ⁽³⁾ , INA199Bx and INA199Cx	GND – 0.1	26	
REF input		GND – 0.3	(V+) + 0.3	V
Output ⁽³⁾		GND – 0.3	(V+) + 0.3	V
Input current into all pins ⁽³⁾			5	mA
Operating temperature		–40	125	°C
Junction temperature			150	°C
Storage temperature, T_{stg}		–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) V_{IN+} and V_{IN-} are the voltages at the IN+ and IN– pins, respectively.

(3) Input voltage at any pin cannot exceed the voltage shown if the current at that pin is limited to 5 mA.

6.2 ESD Ratings

			VALUE	UNIT
INA199A1, INA199A2, and INA199A3 in DCK and RSW Packages				
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	
INA199Bx and INA199Cx in DCK and RSW Packages				
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±3500	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{CM}	Common-mode input voltage		12		V
V _S	Operating supply voltage (applied to V+)		5		V
T _A	Operating free-air temperature	–40		125	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		INA199		UNIT
		DCK (SC70)	RSW (UQFN)	
		6 PINS	10 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	227.3	107.3	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	79.5	56.5	°C/W
R _{θJB}	Junction-to-board thermal resistance	72.1	18.7	°C/W
ψ _{JT}	Junction-to-top characterization parameter	3.6	1.1	°C/W
ψ _{JB}	Junction-to-board characterization parameter	70.4	18.7	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	—	—	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics

at $T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $V_{IN+} = 12\text{ V}$, $V_{SENSE} = V_{IN+} - V_{IN-}$, and $V_{REF} = V_S / 2$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT						
V _{CM}	Common-mode input range	Version A, T _A = −40°C to 125°C	−0.3		26	V
		Version B and C, T _A = −40°C to 125°C	−0.1		26	
CMR	Common-mode rejection	V _{IN+} = 0 V to 26 V, V _{SENSE} = 0 mV, T _A = −40°C to 125°C	100	120		dB
V _{OS}	Offset voltage, RTI ⁽¹⁾	V _{SENSE} = 0 mV		±5	±150	μV
dV _{OS} /dT	V _{OS} vs temperature	T _A = −40°C to 125°C		0.1	0.5	μV/°C
PSR	Power supply rejection	V _S = 2.7 V to 18 V, V _{IN+} = 18 V, V _{SENSE} = 0 mV		±0.1		μV/V
I _B	Input bias current	V _{SENSE} = 0 mV		28		μA
I _{OS}	Input offset current	V _{SENSE} = 0 mV		±0.02		μA
OUTPUT						
G	Gain	INA199x1		50		V/V
		INA199x2		100		
		INA199x3		200		
Gain error		Version A and B, V _{SENSE} = −5 mV to 5 mV, T _A = −40°C to 125°C		±0.03%	±1.5%	
		Version C, V _{SENSE} = −5 mV to 5 mV, T _A = −40°C to 125°C		±0.03%	±1%	
Gain error vs temperature		T _A = −40°C to 125°C		3	10	ppm/°C
Nonlinearity error		V _{SENSE} = −5 mV to 5 mV		±0.01%		
Maximum capacitive load		No sustained oscillation		1		nF
VOLTAGE OUTPUT ⁽²⁾						
Swing to V+ power-supply rail		R _L = 10 kΩ to GND, T _A = −40°C to 125°C		(V+) − 0.05	(V+) − 0.2	V
Swing to GND		R _L = 10 kΩ to GND, T _A = −40°C to 125°C		(V _{GND}) + 0.005	(V _{GND}) + 0.05	V
FREQUENCY RESPONSE						
GBW	Bandwidth	C _{LOAD} = 10 pF, INA199x1		80		kHz
		C _{LOAD} = 10 pF, INA199x2		30		
		C _{LOAD} = 10 pF, INA199x3		14		
SR	Slew rate			0.4		V/μs
NOISE, RTI ⁽¹⁾						
Voltage noise density				25		nV/√ Hz
POWER SUPPLY						
V _S	Operating voltage range	T _A = −40°C to 125°C	2.7		26	V
		−20°C to 85°C	2.5		26	
I _Q	Quiescent current	V _{SENSE} = 0 mV		65	100	μA
I _Q over temperature		T _A = −40°C to 125°C			115	μA
TEMPERATURE RANGE						
Specified range			−40		125	°C
Operating range			−40		125	°C
θ _{JA}	Thermal resistance	SC70		250		°C/W
		UQFN		80		

(1) RTI = Referred-to-input.

(2) See Typical Characteristic curve, *Output Voltage Swing vs Output Current* (Figure 6-6).

6.6 Typical Characteristics

performance measured with the INA199A3 at $T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $V_{IN+} = 12\text{ V}$, and $V_{REF} = V_S / 2$ (unless otherwise noted)

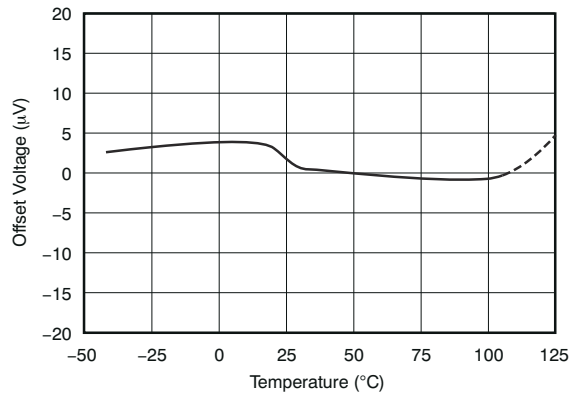


Figure 6-1. Offset Voltage vs Temperature

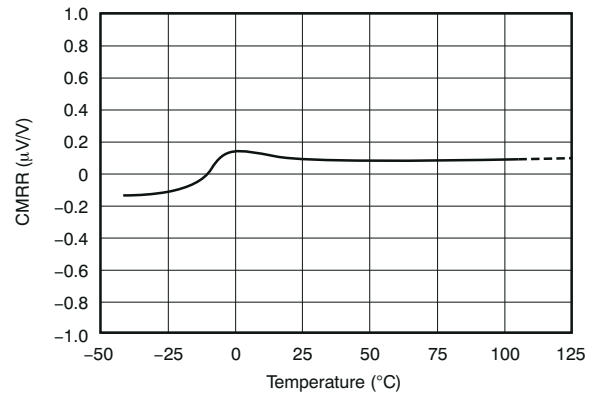


Figure 6-2. Common-Mode Rejection Ratio vs Temperature

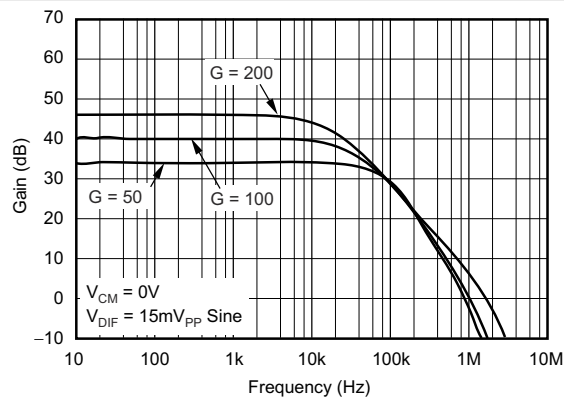


Figure 6-3. Gain vs Frequency

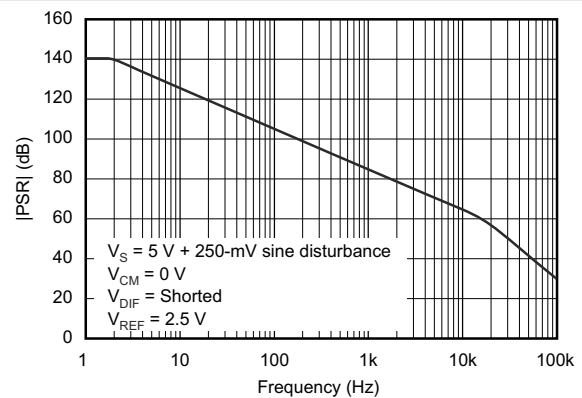


Figure 6-4. Power-Supply Rejection Ratio vs Frequency

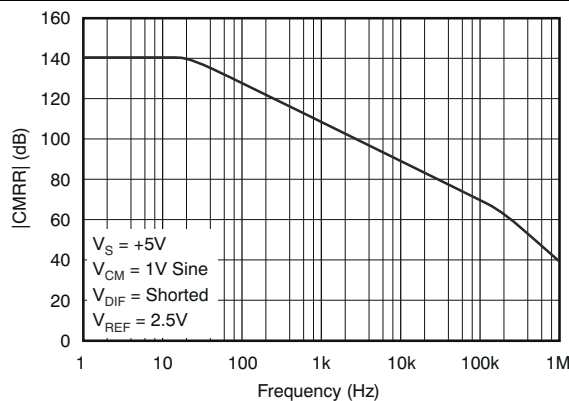


Figure 6-5. Common-Mode Rejection Ratio vs Frequency

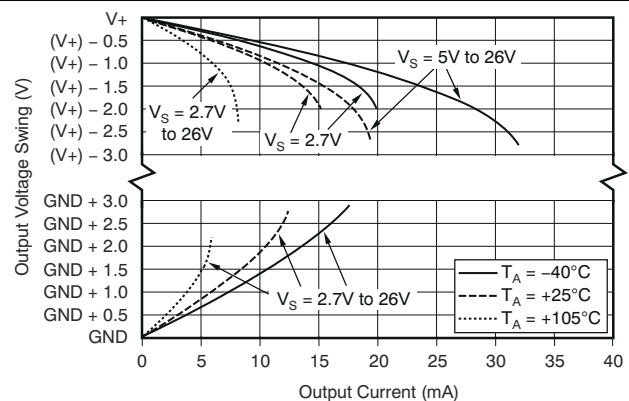


Figure 6-6. Output Voltage Swing vs Output Current

6.6 Typical Characteristics (continued)

performance measured with the INA199A3 at $T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $V_{IN+} = 12\text{ V}$, and $V_{REF} = V_S / 2$ (unless otherwise noted)

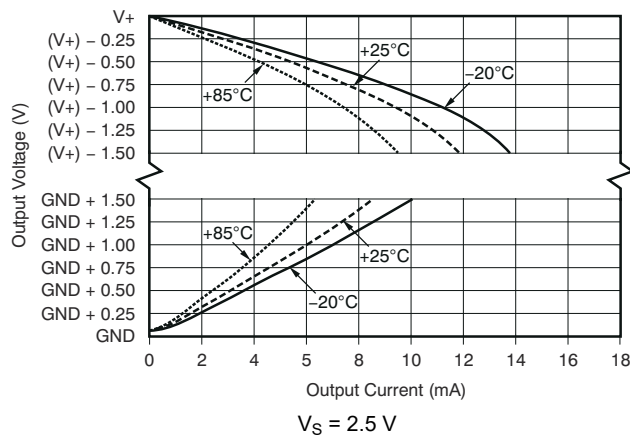


Figure 6-7. Output Voltage Swing vs Output Current

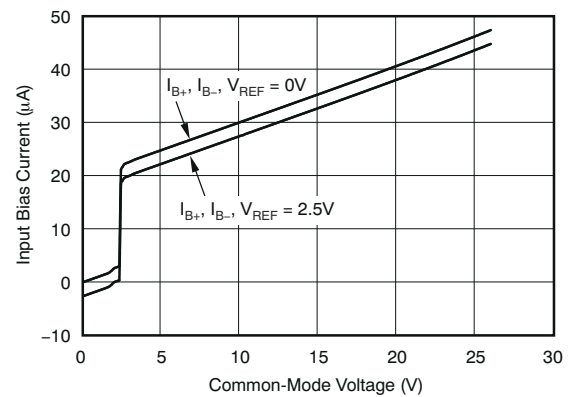


Figure 6-8. Input Bias Current vs Common-Mode Voltage With Supply Voltage = 5 V

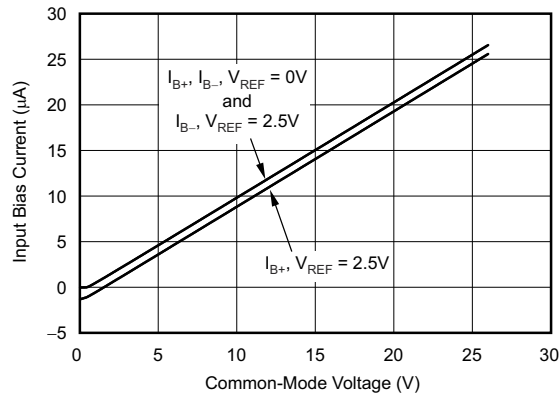


Figure 6-9. Input Bias Current vs Common-Mode Voltage With Supply Voltage = 0 V (Shutdown)

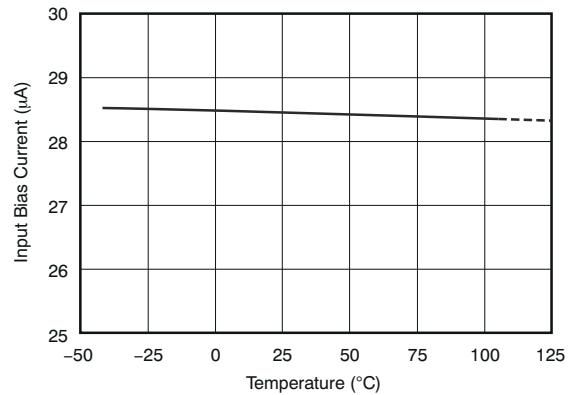


Figure 6-10. Input Bias Current vs Temperature

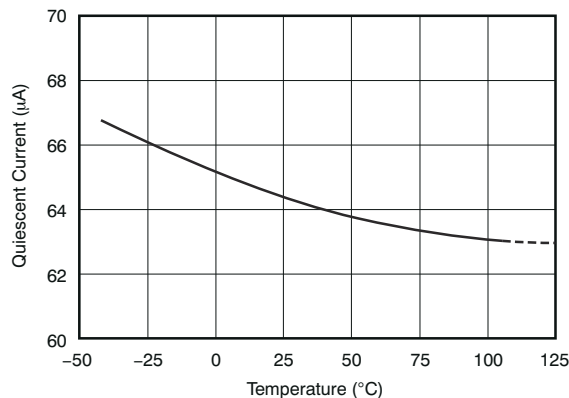


Figure 6-11. Quiescent Current vs Temperature

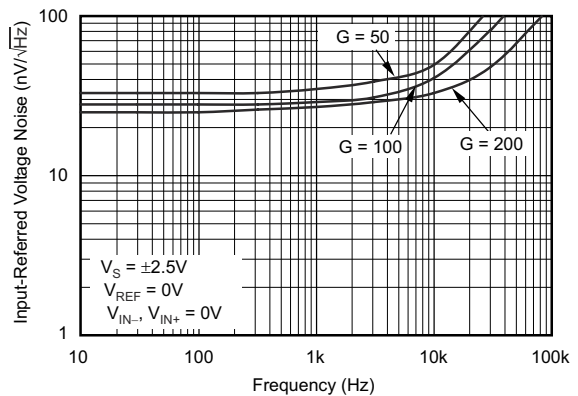


Figure 6-12. Input-Referred Voltage Noise vs Frequency

6.6 Typical Characteristics (continued)

performance measured with the INA199A3 at $T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $V_{IN+} = 12\text{ V}$, and $V_{REF} = V_S / 2$ (unless otherwise noted)

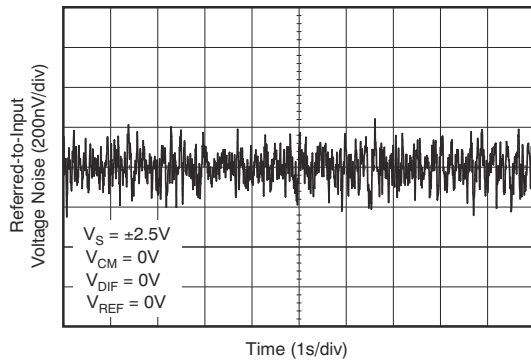


Figure 6-13. 0.1-Hz to 10-Hz Voltage Noise (Referred-to-Input)

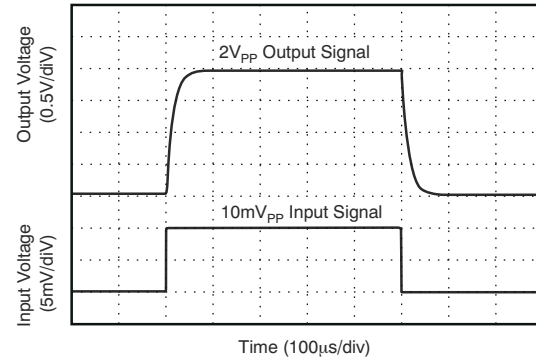


Figure 6-14. Step Response (10-mV_{PP} Input Step)

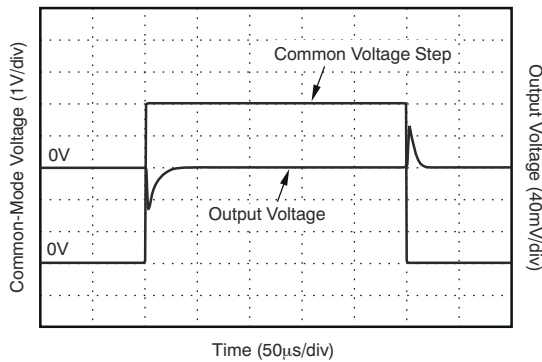


Figure 6-15. Common-Mode Voltage Transient Response

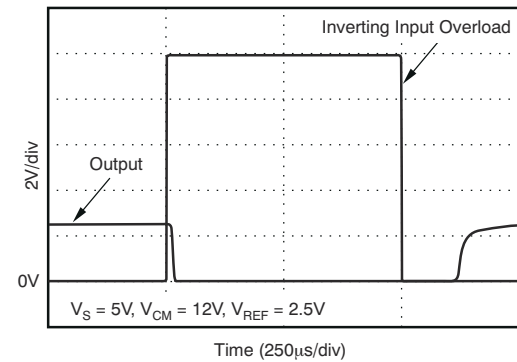


Figure 6-16. Inverting Differential Input Overload

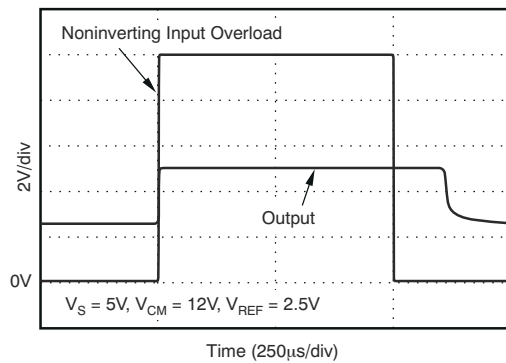


Figure 6-17. Noninverting Differential Input Overload

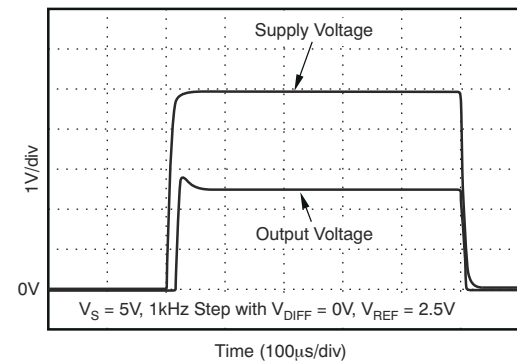


Figure 6-18. Start-Up Response

6.6 Typical Characteristics (continued)

performance measured with the INA199A3 at $T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $V_{IN+} = 12\text{ V}$, and $V_{REF} = V_S / 2$ (unless otherwise noted)

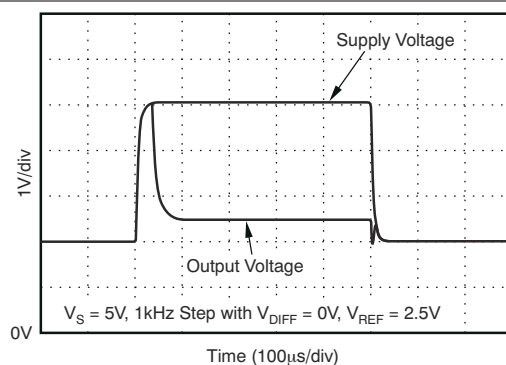


Figure 6-19. Brownout Recovery

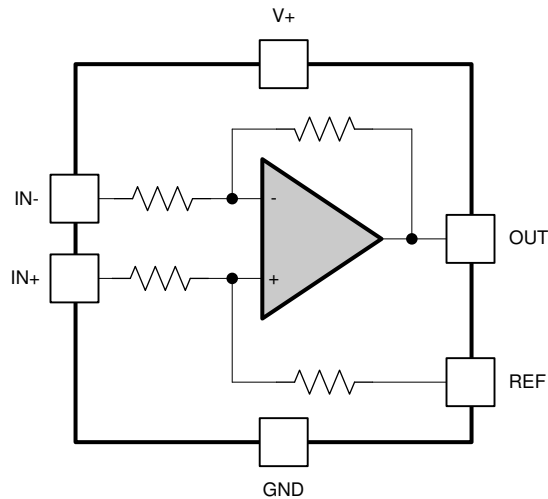
7 Detailed Description

7.1 Overview

The INA199 is a 26-V common mode, zero-drift topology, current-sensing amplifier that can be used in both low-side and high-side configurations. The device is a specially-designed, current-sensing amplifier that is able to accurately measure voltages developed across a current-sensing resistor on common-mode voltages that far exceed the supply voltage powering the device. Current can be measured on input voltage rails as high as 26 V and the device can be powered from supply voltages as low as 2.7 V.

The zero-drift topology enables high-precision measurements with maximum input offset voltages as low as 150 μV with a maximum temperature contribution of 0.5 $\mu\text{V}/^\circ\text{C}$ over the full temperature range of -40°C to $+125^\circ\text{C}$.

7.2 Functional Block Diagram

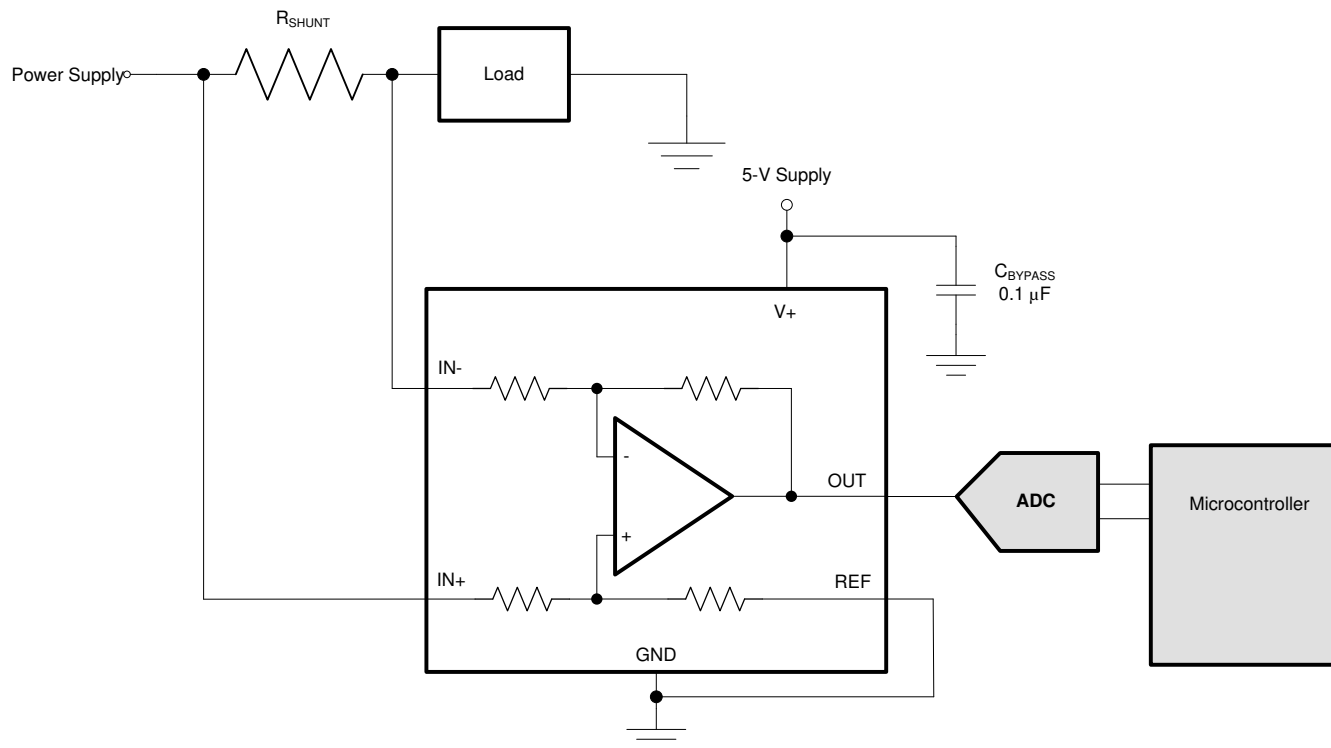


Copyright © 2017, Texas Instruments Incorporated

7.3 Feature Description

7.3.1 Basic Connections

Figure 7-1 shows the basic connections for the INA199. The input pins, IN+ and IN–, must be connected as close as possible to the shunt resistor to minimize any resistance in series with the shunt resistor.



Copyright © 2017, Texas Instruments Incorporated

Figure 7-1. Typical Application

Power-supply bypass capacitors are required for stability. Applications with noisy or high-impedance power supplies may require additional decoupling capacitors to reject power-supply noise. Connect bypass capacitors close to the device pins.

On the RSW package, two pins are provided for each input. These pins must be tied together (that is, tie IN+ to IN+ and tie IN– to IN–).

7.3.2 Selecting R_S

The zero-drift offset performance of the INA199 offers several benefits. Most often, the primary advantage of the low offset characteristic enables lower full-scale drops across the shunt. For example, non-zero-drift current shunt monitors typically require a full-scale range of 100 mV.

The INA199 series gives equivalent accuracy at a full-scale range on the order of 10 mV. This accuracy reduces shunt dissipation by an order of magnitude with many additional benefits.

Alternatively, there are applications that must measure current over a wide dynamic range that can take advantage of the low offset on the low end of the measurement. Most often, these applications can use the lower gain of 50 or 100 to accommodate larger shunt drops on the upper end of the scale. For instance, an INA199A1 operating on a 3.3-V supply can easily handle a full-scale shunt drop of 60 mV, with only 150 μ V of offset.

7.4 Device Functional Modes

7.4.1 Input Filtering

An obvious and straightforward filtering location is at the device output. However, this location negates the advantage of the low output impedance of the internal buffer. The only other filtering option is at the device input pins. This location, though, does require consideration of the $\pm 30\%$ tolerance of the internal resistances. Figure 7-2 shows a filter placed at the inputs pins.

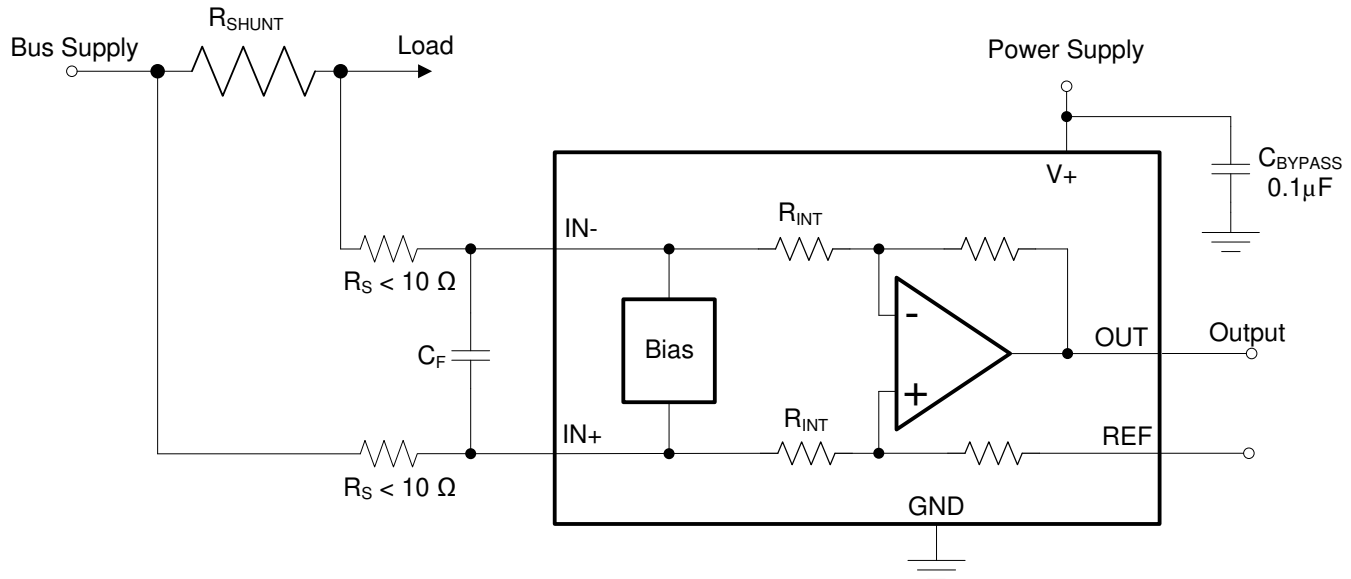


Figure 7-2. Filter at Input Pins

The addition of external series resistance, however, creates an additional error in the measurement so the value of these series resistors must be kept to 10 Ω (or less if possible) to reduce any affect to accuracy. The internal bias network shown in Figure 7-2 present at the input pins creates a mismatch in input bias currents when a differential voltage is applied between the input pins. If additional external series filter resistors are added to the circuit, the mismatch in bias currents results in a mismatch of voltage drops across the filter resistors. This mismatch creates a differential error voltage that subtracts from the voltage developed at the shunt resistor. This error results in a voltage at the device input pins that is different than the voltage developed across the shunt resistor. Without the additional series resistance, the mismatch in input bias currents has little effect on device operation. The amount of error these external filter resistor add to the measurement can be calculated using Equation 2 where the gain error factor is calculated using Equation 1.

The amount of variance in the differential voltage present at the device input relative to the voltage developed at the shunt resistor is based both on the external series resistance value as well as the internal input resistors, R3 and R4 (or R_INT as shown in Figure 7-2). The reduction of the shunt voltage reaching the device input pins appears as a gain error when comparing the output voltage relative to the voltage across the shunt resistor. A factor can be calculated to determine the amount of gain error that is introduced by the addition of external series resistance. The equation used to calculate the expected deviation from the shunt voltage to what is seen at the device input pins is given in Equation 1:

$$\text{Gain Error Factor} = \frac{(1250 \times R_{\text{INT}})}{(1250 \times R_S) + (1250 \times R_{\text{INT}}) + (R_S \times R_{\text{INT}})} \quad (1)$$

where:

- R_INT is the internal input resistor (R3 and R4).
- R_S is the external series resistance.

With the adjustment factor equation including the device internal input resistance, this factor varies with each gain version, as listed in [Table 7-1](#). Each individual device gain error factor is listed in [Table 7-2](#).

Table 7-1. Input Resistance

PRODUCT	GAIN	R _{INT} (kΩ)
INA199x1	50	20
INA199x2	100	10
INA199x3	200	5

Table 7-2. Device Gain Error Factor

PRODUCT	SIMPLIFIED GAIN ERROR FACTOR
INA199x1	$\frac{20,000}{(17 \times R_S) + 20,000}$
INA199x2	$\frac{10,000}{(9 \times R_S) + 10,000}$
INA199x3	$\frac{1000}{R_S + 1000}$

The gain error that can be expected from the addition of the external series resistors can then be calculated based on [Equation 2](#):

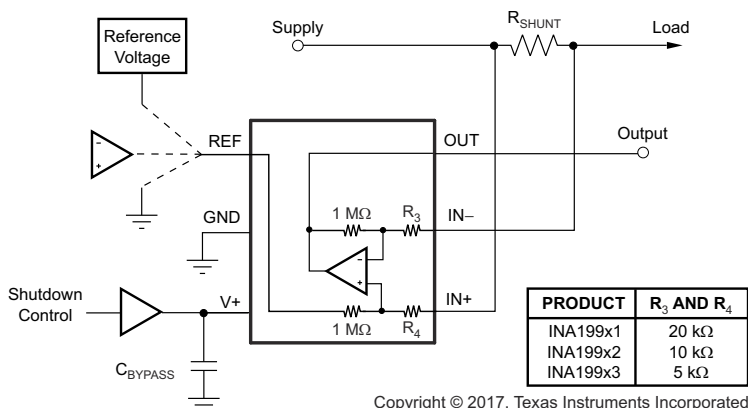
$$\text{Gain Error (\%)} = 100 - (100 \times \text{Gain Error Factor}) \quad (2)$$

For example, using an INA199x2 and the corresponding gain error equation from [Table 7-2](#), a series resistance of 10-Ω results in a gain error factor of 0.991. The corresponding gain error is then calculated using [Equation 2](#), resulting in a gain error of approximately 0.89% solely because of the external 10-Ω series resistors. Using an INA199x1 with the same 10-Ω series resistor results in a gain error factor of 0.991 and a gain error of 0.84% again solely because of these external resistors.

7.4.2 Shutting Down the INA199 Series

Although the INA199 series does not have a shutdown pin, the low power consumption of the device allows the output of a logic gate or transistor switch to power the INA199. This gate or switch turns on and turns off the INA199 power-supply quiescent current.

However, in current shunt monitoring applications, there is also a concern for how much current is drained from the shunt circuit in shutdown conditions. Evaluating this current drain involves considering the simplified schematic of the INA199 in shutdown mode shown in [Figure 7-3](#).



Copyright © 2017, Texas Instruments Incorporated

1-MΩ paths from shunt inputs to reference and the INA199 outputs.

Figure 7-3. Basic Circuit for Shutting Down the INA199 With a Grounded Reference

There is typically slightly more than 1-M Ω impedance (from the combination of 1-M Ω feedback and 5-k Ω input resistors) from each input of the INA199 to the OUT pin and to the REF pin. The amount of current flowing through these pins depends on the respective ultimate connection. For example, if the REF pin is grounded, the calculation of the effect of the 1-M Ω impedance from the shunt to ground is straightforward. However, if the reference or operational amplifier is powered when the INA199 is shut down, the calculation is direct; instead of assuming 1-M Ω to ground, however, assume 1-M Ω to the reference voltage. If the reference or operational amplifier is also shut down, some knowledge of the reference or operational amplifier output impedance under shutdown conditions is required. For instance, if the reference source functions as an open circuit when not powered, little or no current flows through the 1-M Ω path.

Regarding the 1-M Ω path to the output pin, the output stage of a disabled INA199 does constitute a good path to ground. Consequently, this current is directly proportional to a shunt common-mode voltage impressed across a 1-M Ω resistor.

Note

When the device is powered up, there is an additional, nearly constant, and well-matched 25 μ A that flows in each of the inputs as long as the shunt common-mode voltage is 3 V or higher. Below 2-V common-mode, the only current effects are the result of the 1-M Ω resistors.

7.4.3 REF Input Impedance Effects

As with any difference amplifier, the INA199 series common-mode rejection ratio is affected by any impedance present at the REF input. This concern is not a problem when the REF pin is connected directly to most references or power supplies. When using resistive dividers from the power supply or a reference voltage, the REF pin must be buffered by an operational amplifier.

In systems where the INA199 output can be sensed differentially, such as by a differential input analog-to-digital converter (ADC) or by using two separate ADC inputs, the effects of external impedance on the REF input can be cancelled. [Figure 7-4](#) depicts a method of taking the output from the INA199 by using the REF pin as a reference.

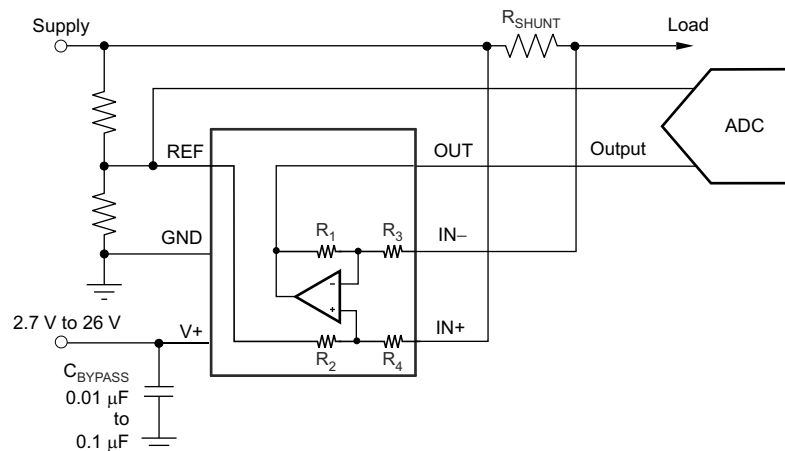


Figure 7-4. Sensing the INA199 to Cancel Effects of Impedance on the REF Input

7.4.4 Using the INA199 With Common-Mode Transients Above 26 V

With a small amount of additional circuitry, the INA199 series can be used in circuits subject to transients higher than 26 V, such as automotive applications. Use only Zener diode or Zener-type transient absorbers (sometimes referred to as *transzorbs*); any other type of transient absorber has an unacceptable time delay. Start by adding a pair of resistors (see [Figure 7-5](#)) as a working impedance for the Zener. Keeping these resistors as small as possible is preferable, most often approximately 10 Ω . Larger values can be used with an effect on gain as discussed in the [Section 7.4.1](#) section. Because this circuit limits only short-term transients, many applications

are satisfied with a 10-Ω resistor along with conventional Zener diodes of the lowest power rating that can be found. This combination uses the least amount of board space. These diodes can be found in packages as small as SOT-523 or SOD-523. See *TIDA-00302 Transient Robustness for Current Shunt Monitor Design Guide*, [TIDU473](#) for more information on transient robustness and current-shunt monitor input protection.

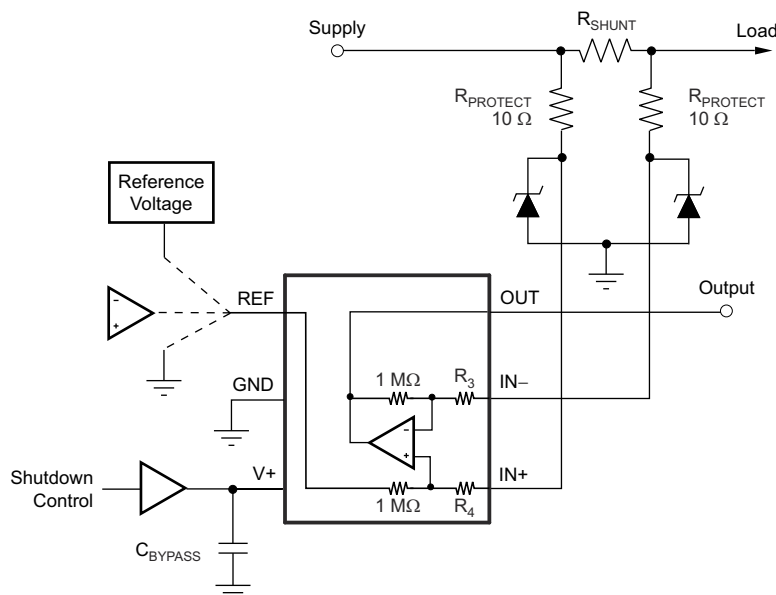


Figure 7-5. INA199 Transient Protection Using Dual Zener Diodes

In the event that low-power zeners do not have sufficient transient absorption capability and a higher power transzorb must be used, the most package-efficient solution then involves using a single transzorb and back-to-back diodes between the device inputs. The most space-efficient solutions are dual series-connected diodes in a single SOT-523 or SOD-523 package. This method is shown in [Figure 7-6](#). In either of these examples, the total board area required by the INA199 with all protective components is less than that of an SO-8 package, and only slightly greater than that of an MSOP-8 package.

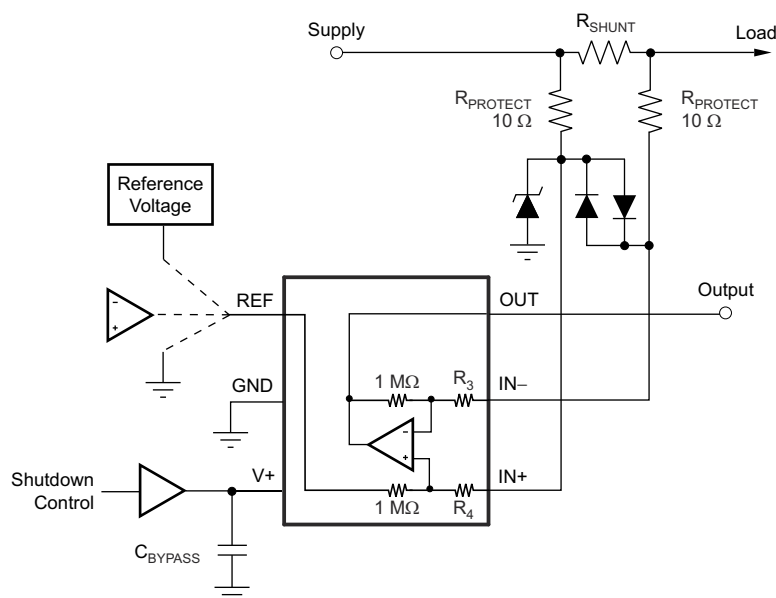


Figure 7-6. INA199 Transient Protection Using a Single Transzorb and Input Clamps

7.4.5 Improving Transient Robustness

Applications involving large input transients with excessive dV/dt above 2 kV per microsecond present at the device input pins can cause damage to the internal ESD structures on version A devices. This potential damage is a result of the internal latching of the ESD structure to ground when this transient occurs at the input. With significant current available in most current-sensing applications, the large current flowing through the input transient-triggered, ground-shorted ESD structure quickly results in damage to the silicon. External filtering can be used to attenuate the transient signal prior to reaching the inputs to avoid the latching condition. Take care to ensure that external series input resistance does not significantly affect gain error accuracy. For accuracy purposes, keep the resistance under 10 Ω if possible. Ferrite beads are recommended for this filter because of their inherently low dc ohmic value. Ferrite beads with less than 10 Ω of resistance at dc and over 600 Ω of resistance at 100 MHz to 200 MHz are recommended. The recommended capacitor values for this filter are between 0.01 μF and 0.1 μF to ensure adequate attenuation in the high-frequency region. This protection scheme is shown in Figure 7-7. Again, see *TIDA-00302 Transient Robustness for Current Shunt Monitor Design Guide*, TIDU473 for more information on transient robustness and current-shunt monitor input protection.

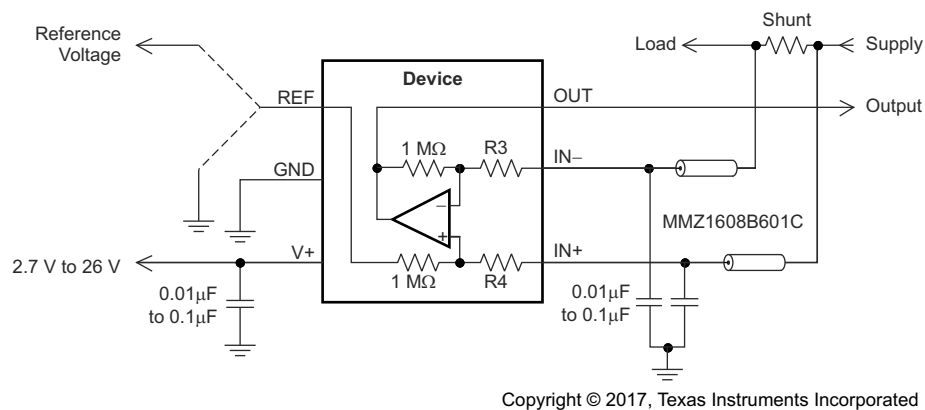


Figure 7-7. Transient Protection

To minimize the cost of adding these external components to protect the device in applications where large transient signals may be present, version B and C devices are now available with new ESD structures that are not susceptible to this latching condition. Version B and C devices are incapable of sustaining these damage-causing latched conditions so these devices do not have the same sensitivity to the transients that the version A devices have, thus making the version B and C devices a better fit for these applications.

8 Application and Implementation

Note

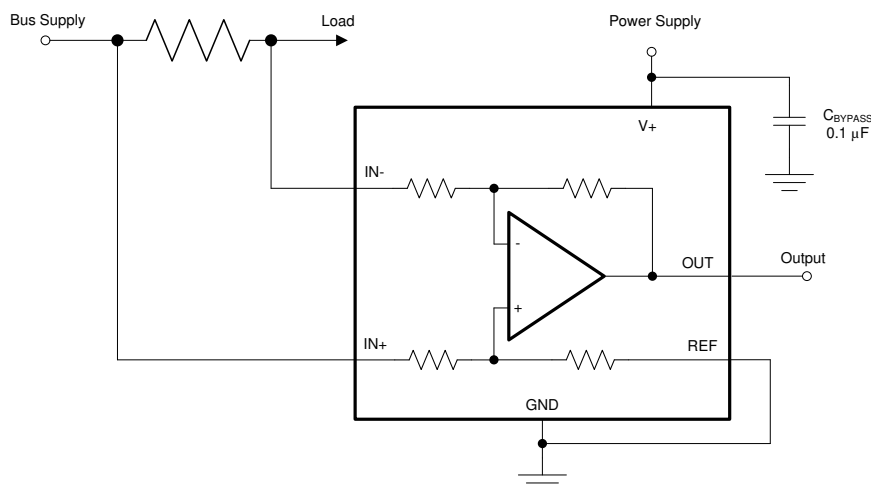
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The INA199 measures the voltage developed across a current-sensing resistor when current passes through it. The ability to drive the reference pin to adjust the functionality of the output signal offers multiple configurations, as discussed throughout this section.

8.2 Typical Applications

8.2.1 Unidirectional Operation



Copyright © 2017, Texas Instruments Incorporated

Figure 8-1. Unidirectional Application Schematic

8.2.1.1 Design Requirements

The device can be configured to monitor current flowing in one direction (unidirectional) or in both directions (bidirectional) depending on how the REF pin is configured. The most common case is unidirectional where the output is set to ground when no current is flowing by connecting the REF pin to ground, as shown in [Figure 8-1](#). When the input signal increases, the output voltage at the OUT pin increases.

8.2.1.2 Detailed Design Procedure

The linear range of the output stage is limited in how close the output voltage can approach ground under zero input conditions. In unidirectional applications where measuring very low input currents is desirable, bias the REF pin to a convenient value above 50 mV to get the output into the linear range of the device. To limit common-mode rejection errors, TI recommends buffering the reference voltage connected to the REF pin.

A less frequently-used output biasing method is to connect the REF pin to the supply voltage, V+. This method results in the output voltage saturating at 200 mV below the supply voltage when no differential input signal is present. This method is similar to the output saturated low condition with no input signal when the REF pin is connected to ground. The output voltage in this configuration only responds to negative currents that develop negative differential input voltage relative to the device IN- pin. Under these conditions, when the differential

input signal increases negatively, the output voltage moves downward from the saturated supply voltage. The voltage applied to the REF pin must not exceed the device supply voltage.

8.2.1.3 Application Curve

An example output response of a unidirectional configuration is shown in Figure 8-2. With the REF pin connected directly to ground, the output voltage is biased to this zero output level. The output rises above the reference voltage for positive differential input signals but cannot fall below the reference voltage for negative differential input signals because of the grounded reference voltage.

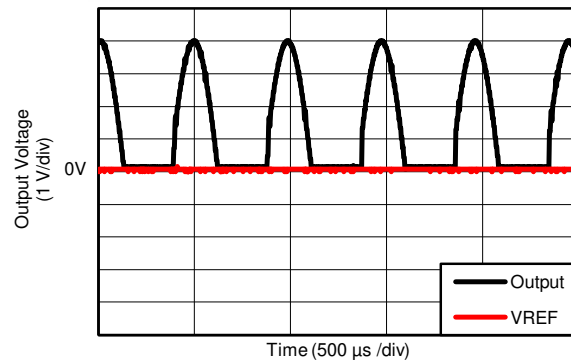
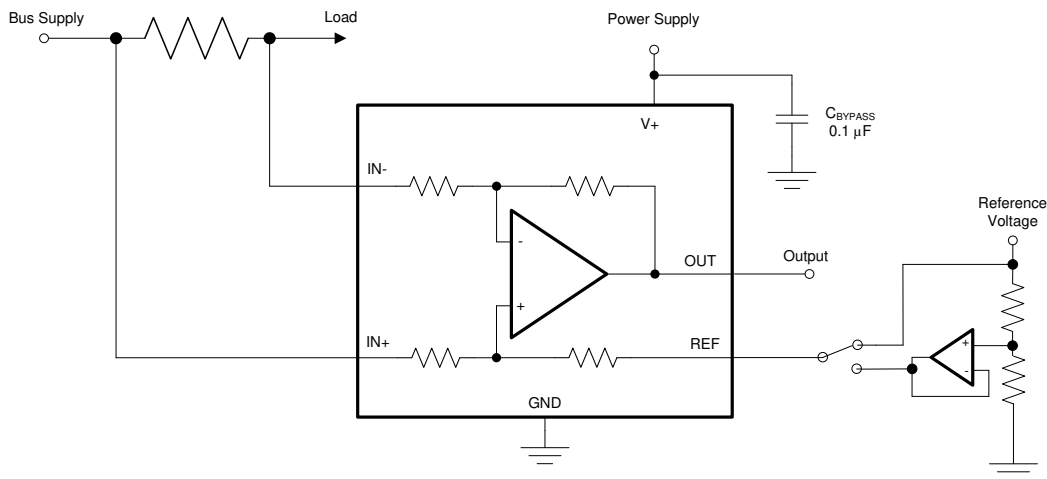


Figure 8-2. Unidirectional Application Output Response

8.2.2 Bidirectional Operation



Copyright © 2017, Texas Instruments Incorporated

Figure 8-3. Bidirectional Application Schematic

8.2.2.1 Design Requirements

The device is a bidirectional, current-sense amplifier capable of measuring currents through a resistive shunt in two directions. This bidirectional monitoring is common in applications that include charging and discharging operations where the current flow-through resistor can change directions.

8.2.2.2 Detailed Design Procedure

The ability to measure this current flowing in both directions is enabled by applying a voltage to the REF pin; see Figure 8-3. The voltage applied to REF (V_{REF}) sets the output state that corresponds to the zero-input level

state. The output then responds by increasing above V_{REF} for positive differential signals (relative to the $IN-$ pin) and responds by decreasing below V_{REF} for negative differential signals. This reference voltage applied to the REF pin can be set anywhere between 0 V to $V+$. For bidirectional applications, V_{REF} is typically set at mid-scale for equal signal range in both current directions. In some cases, however, V_{REF} is set at a voltage other than mid-scale when the bidirectional current and corresponding output signal do not need to be symmetrical.

8.2.2.3 Application Curve

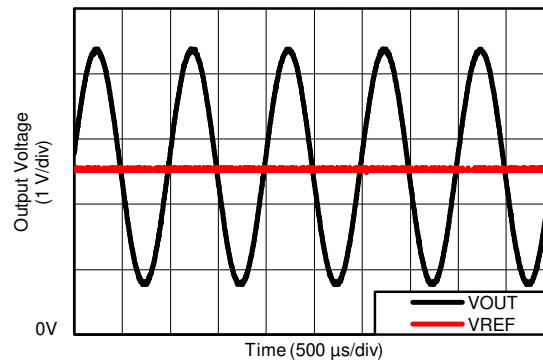


Figure 8-4. Bidirectional Application Output Response

9 Power Supply Recommendations

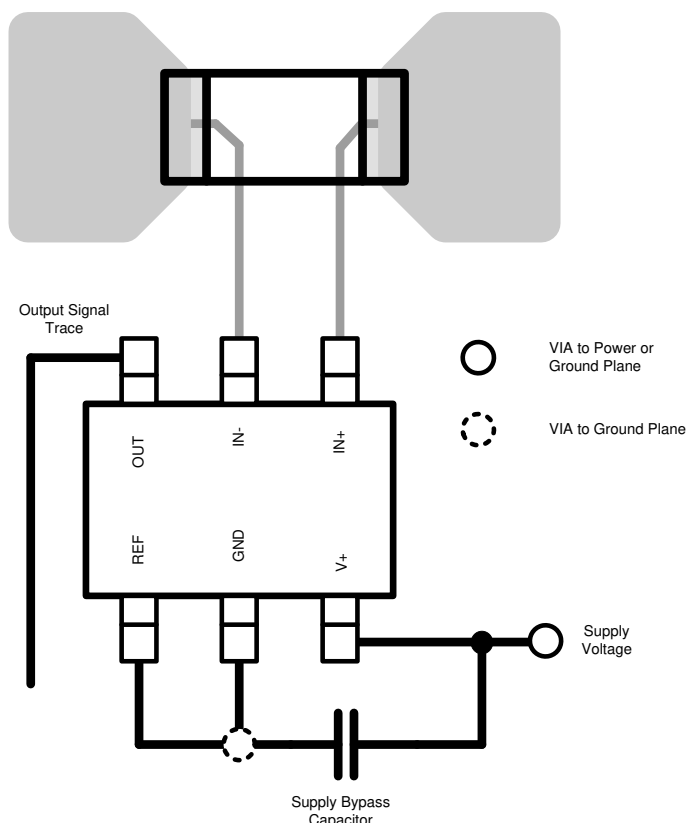
The input circuitry of the INA199 can accurately measure beyond its power-supply voltage, $V+$. For example, the $V+$ power supply can be 5 V, whereas the load power-supply voltage can be as high as 26 V. However, the output voltage range of the OUT pin is limited by the voltages on the power-supply pin. Also, the INA199 can withstand the full input signal range up to 26-V range in the input pins, regardless of whether the device has power applied or not.

10 Layout

10.1 Layout Guidelines

- Connect the input pins to the sensing resistor using a kelvin or 4-wire connection. This connection technique ensures that only the current-sensing resistor impedance is detected between the input pins. Poor routing of the current-sensing resistor commonly results in additional resistance present between the input pins. Given the very low ohmic value of the current resistor, any additional high-current carrying impedance can cause significant measurement errors.
- Place the power-supply bypass capacitor as close as possible to the supply and ground pins. TI recommends using a bypass capacitor with a value of 0.1 μF . Additional decoupling capacitance can be added to compensate for noisy or high-impedance power supplies.

10.2 Layout Example



Copyright © 2017, Texas Instruments Incorporated

Figure 10-1. Recommended Layout

11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

For related documentation see the following:

- [INA199A1-A3EVM User's Guide](#)
- [TIDA-00302 Transient Robustness for Current Shunt Monitor](#)

11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.3 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

11.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

11.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

12 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision G (February 2017) to Revision H (October 2023)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document.....	1
Changes from Revision F (June 2016) to Revision G (February 2017)	Page
• Changed first sub-bullet of <i>Accuracy Features</i> bullet: deleted $\pm 1.5\%$ from sub-bullet and added version differences	1
• Changed 105°C to 125°C in last paragraph of <i>Description</i> section	1
• Added <i>INA199Cx</i> to last row of <i>Analog inputs</i> in <i>Absolute Maximum Ratings</i> table.....	4
• Changed <i>INA199Ax</i> HBM value from ± 4000 to ± 2000 and changed <i>INA199B1</i> , <i>INA199B2</i> , and <i>INA199B3</i> to <i>INA199Bx</i> and <i>INA199Cx</i> in second V_{ESD} section of <i>ESD Ratings</i> table.....	4
• Changed maximum specification from 105 to 125 in T_A row of <i>Recommended Operating Conditions</i> table.....	5
• Changed all $T_A = -40^{\circ}\text{C}$ to 105°C to $T_A = -40^{\circ}\text{C}$ to 125°C in <i>Electrical Characteristics</i> table.....	6
• Added version C to last row of V_{CM} parameter in <i>Electrical Characteristics</i> table	6
• Added versions A and B to first <i>Gain error</i> parameter row, added second row	6
• Changed devices listed in test conditions of GBW parameter in <i>Electrical Characteristics</i> table to <i>INA199x1</i> , <i>INA199x2</i> , and <i>INA199x3</i> , respectively for the three rows.....	6
• Changed maximum specification from 105 to 125 in <i>Specified range</i> parameter of <i>Electrical Characteristics</i> table.....	6
• Changed 105°C to 125°C in last paragraph of <i>Overview</i> section.....	11
• Changed <i>INA199A2</i> and <i>INA199B2</i> to <i>INA199x2</i> and changed <i>INA199A2</i> and <i>INA199B2</i> to <i>INA199x2</i> in last paragraph of <i>Input Filtering</i> section.....	13
• Changed listed products in table of Figure 22	14
• Changed <i>version B</i> to <i>version B and C</i> in second paragraph of <i>Improving Transient Robustness</i> section.....	17
Changes from Revision E (December 2015) to Revision F (June 2016)	Page
• Changed <i>Package Features</i> bullet to include pin count for both packages	1
• Deleted last <i>Applications</i> bullet.....	1
• Changed <i>Description</i> section.....	1
• Changed <i>Analog inputs</i> parameter in <i>Absolute Maximum Ratings</i> table.....	4
• Changed <i>ESD Ratings</i> table: deleted both <i>Machine model</i> rows, changed <i>INA199B</i> HBM specification.....	4
• Changed <i>Electrical Characteristics</i> table: recombined the two <i>Electrical Characteristics</i> tables into one	6
• Added minimum specification to second row of Power Supply, V_S parameter in <i>Electrical Characteristics</i> table	6
• Added θ_{JA} parameter back to <i>Electrical Characteristics</i> table	6
Changes from Revision D (November 2012) to Revision E (December 2015)	Page
• Added <i>ESD Ratings</i> table, <i>Thermal Information</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i> , <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section	1
Changes from Revision C (August 2012) to Revision D (November 2012)	Page
• Changed Frequency Response, <i>Bandwidth</i> parameter in <i>Electrical Characteristics</i> table.....	6
• Updated Figure 7-2	13
• Updated Figure 7-3	14
Changes from Revision B (February 2010) to Revision C (August 2012)	Page
• Added <i>INA199Bx</i> gains to fourth <i>Features</i> bullet.....	1
• Added <i>INA199Bx</i> data to Product Family Table.....	3
• Added <i>INA199Bx</i> data to Package Information table.....	3

• Added silicon version B data to Input, <i>Common-Mode Input Range</i> parameter of Electrical Characteristics table.....	6
• Added QFN package information to <i>Temperature Range</i> section of <i>Electrical Characteristics</i> table.....	6
• Updated Figure 6-3	7
• Updated Figure 6-9	7
• Updated Figure 6-12	7
• Changed last paragraph of the <i>Selecting R_S</i> section to cover both INA199Ax and INA199Bx versions.....	12
• Changed <i>Input Filtering</i> section.....	13
• Added <i>Improving Transient Robustness</i> section.....	17

Changes from Revision A (June 2009) to Revision B (February 2010)	Page
--	-------------

• Deleted ordering information content from Package/Ordering table.....	3
• Updated DCK pinout drawing.....	3

Changes from Revision * (April 2009) to Revision A (June 2009)	Page
---	-------------

• Added <i>ordering number</i> and <i>transport media, quantity</i> columns to <i>Package/Ordering Information</i> table.....	3
---	---

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
INA199A1DCKR	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU SN NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OBG
INA199A1DCKR.A	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	OBG
INA199A1DCKR.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	OBG
INA199A1DCKRG4	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OBG
INA199A1DCKRG4.A	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OBG
INA199A1DCKRG4.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OBG
INA199A1DCKT	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	NIPDAU SN NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OBG
INA199A1DCKT.A	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	OBG
INA199A1DCKT.B	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	OBG
INA199A1RSWR	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	NSJ
INA199A1RSWR.A	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	NSJ
INA199A1RSWR.B	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	NSJ
INA199A1RSWRG4	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	NSJ
INA199A1RSWRG4.A	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	NSJ
INA199A1RSWRG4.B	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	NSJ
INA199A1RSWT	Last Time Buy	Production	UQFN (RSW) 10	250 SMALL T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	NSJ
INA199A2DCKR	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU SN NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OBH
INA199A2DCKR.A	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	OBH
INA199A2DCKR.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	OBH
INA199A2DCKT	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	NIPDAU SN NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OBH
INA199A2DCKT.A	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	OBH
INA199A2DCKT.B	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	OBH
INA199A2DCKTG4	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	NIPDAU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OBH
INA199A2DCKTG4.A	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OBH
INA199A2DCKTG4.B	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OBH
INA199A2RSWR	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	NTJ
INA199A2RSWR.A	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	NTJ
INA199A2RSWR.B	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	NTJ

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
INA199A2RSWT	Obsolete	Production	UQFN (RSW) 10	-	-	Call TI	Call TI	-40 to 125	NTJ
INA199A3DCKR	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU SN NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OBI
INA199A3DCKR.A	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	OBI
INA199A3DCKR.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	OBI
INA199A3DCKRG4	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OBI
INA199A3DCKRG4.A	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OBI
INA199A3DCKRG4.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OBI
INA199A3DCKT	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	NIPDAU SN NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OBI
INA199A3DCKT.A	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	OBI
INA199A3DCKT.B	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	OBI
INA199A3RSWR	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	NUJ
INA199A3RSWR.A	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	NUJ
INA199A3RSWR.B	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	NUJ
INA199A3RSWRG4	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	NUJ
INA199A3RSWRG4.A	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	NUJ
INA199A3RSWRG4.B	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	NUJ
INA199B1DCKR	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	SEB
INA199B1DCKR.A	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEB
INA199B1DCKR.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEB
INA199B1DCKRG4.A	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
INA199B1DCKRG4.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
INA199B1DCKT	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	SEB
INA199B1DCKT.A	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEB
INA199B1DCKT.B	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEB
INA199B1DCKTG4	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SEB
INA199B1DCKTG4.A	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SEB
INA199B1DCKTG4.B	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SEB
INA199B1RSWR	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHV
INA199B1RSWR.A	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHV
INA199B1RSWR.B	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHV
INA199B1RSWT	Obsolete	Production	UQFN (RSW) 10	-	-	Call TI	Call TI	-40 to 125	SHV

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
INA199B2DCKR	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	SEG
INA199B2DCKR.A	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEG
INA199B2DCKR.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEG
INA199B2DCKRG4	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SEG
INA199B2DCKRG4.A	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SEG
INA199B2DCKRG4.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SEG
INA199B2DCKT	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	SEG
INA199B2DCKT.A	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEG
INA199B2DCKT.B	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEG
INA199B2RSWR	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHW
INA199B2RSWR.A	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHW
INA199B2RSWR.B	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHW
INA199B3DCKR	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	SHE
INA199B3DCKR.A	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SHE
INA199B3DCKR.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SHE
INA199B3DCKT	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	SHE
INA199B3DCKT.A	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SHE
INA199B3DCKT.B	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SHE
INA199B3RSWR	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHX
INA199B3RSWR.A	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHX
INA199B3RSWR.B	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHX
INA199B3RSWRG4	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHX
INA199B3RSWRG4.A	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHX
INA199B3RSWRG4.B	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHX
INA199C1DCKR	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	16L
INA199C1DCKR.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	16L
INA199C1DCKT	Obsolete	Production	SC70 (DCK) 6	-	-	Call TI	Call TI	-40 to 125	16L
INA199C1RSWR	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(160, 16O)
INA199C1RSWR.B	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(160, 16O)
INA199C1RSWRG4	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	160
INA199C1RSWRG4.B	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	160

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
INA199C1RSWT	Obsolete	Production	UQFN (RSW) 10	-	-	Call TI	Call TI	-40 to 125	(160, 16O)
INA199C2DCKR	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	16M
INA199C2DCKR.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	16M
INA199C2DCKT	Obsolete	Production	SC70 (DCK) 6	-	-	Call TI	Call TI	-40 to 125	16M
INA199C2RSWR	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16P
INA199C2RSWR.B	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16P
INA199C2RSWT	Obsolete	Production	UQFN (RSW) 10	-	-	Call TI	Call TI	-40 to 125	16P
INA199C3DCKR	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	16N
INA199C3DCKR.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	16N
INA199C3DCKT	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	16N
INA199C3DCKT.B	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	16N
INA199C3RSWR	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16Q
INA199C3RSWR.B	Active	Production	UQFN (RSW) 10	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16Q
INA199C3RSWT	Obsolete	Production	UQFN (RSW) 10	-	-	Call TI	Call TI	-40 to 125	16Q

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF INA199 :

- Automotive : [INA199-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA199A1DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199A1DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199A1DCKRG4	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199A1DCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199A1DCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199A1DCKT	SC70	DCK	6	250	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
INA199A1RSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA199A1RSWR	UQFN	RSW	10	3000	179.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA199A1RSWRG4	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA199A1RSWT	UQFN	RSW	10	250	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA199A2DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199A2DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199A2DCKR	SC70	DCK	6	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
INA199A2DCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199A2DCKT	SC70	DCK	6	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
INA199A2DCKT	SC70	DCK	6	250	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA199A2DCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199A2DCKTG4	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199A2DCKTG4	SC70	DCK	6	250	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
INA199A2DCKTG4	SC70	DCK	6	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
INA199A2RSWR	UQFN	RSW	10	3000	179.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA199A2RSWR	UQFN	RSW	10	3000	180.0	9.5	1.6	2.0	0.8	4.0	8.0	Q1
INA199A2RSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA199A3DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199A3DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199A3DCKRG4	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199A3DCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199A3DCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199A3RSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA199A3RSWRG4	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA199B1DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199B1DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199B1DCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199B1DCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199B1DCKTG4	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199B1RSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA199B2DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199B2DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199B2DCKRG4	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199B2DCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199B2DCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199B2RSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA199B3DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199B3DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199B3DCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199B3DCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199B3RSWR	UQFN	RSW	10	3000	179.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA199B3RSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA199B3RSWRG4	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA199C1DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199C1DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199C1RSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA199C1RSWRG4	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA199C2DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199C2DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199C2RSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA199C3DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA199C3DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199C3DCKT	SC70	DCK	6	250	178.0	8.4	2.4	2.5	1.2	4.0	8.0	Q3
INA199C3DCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199C3RSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA199A1DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA199A1DCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA199A1DCKRG4	SC70	DCK	6	3000	180.0	180.0	18.0
INA199A1DCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA199A1DCKT	SC70	DCK	6	250	180.0	180.0	18.0
INA199A1DCKT	SC70	DCK	6	250	213.0	191.0	35.0
INA199A1RSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA199A1RSWR	UQFN	RSW	10	3000	200.0	183.0	25.0
INA199A1RSWRG4	UQFN	RSW	10	3000	210.0	185.0	35.0
INA199A1RSWT	UQFN	RSW	10	250	210.0	185.0	35.0
INA199A2DCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA199A2DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA199A2DCKR	SC70	DCK	6	3000	213.0	191.0	35.0
INA199A2DCKT	SC70	DCK	6	250	180.0	180.0	18.0
INA199A2DCKT	SC70	DCK	6	250	223.0	270.0	35.0
INA199A2DCKT	SC70	DCK	6	250	213.0	191.0	35.0
INA199A2DCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA199A2DCKTG4	SC70	DCK	6	250	180.0	180.0	18.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA199A2DCKTG4	SC70	DCK	6	250	213.0	191.0	35.0
INA199A2DCKTG4	SC70	DCK	6	250	223.0	270.0	35.0
INA199A2RSWR	UQFN	RSW	10	3000	200.0	183.0	25.0
INA199A2RSWR	UQFN	RSW	10	3000	189.0	185.0	36.0
INA199A2RSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA199A3DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA199A3DCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA199A3DCKRG4	SC70	DCK	6	3000	180.0	180.0	18.0
INA199A3DCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA199A3DCKT	SC70	DCK	6	250	180.0	180.0	18.0
INA199A3RSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA199A3RSWRG4	UQFN	RSW	10	3000	210.0	185.0	35.0
INA199B1DCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA199B1DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA199B1DCKT	SC70	DCK	6	250	180.0	180.0	18.0
INA199B1DCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA199B1DCKTG4	SC70	DCK	6	250	180.0	180.0	18.0
INA199B1RSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA199B2DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA199B2DCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA199B2DCKRG4	SC70	DCK	6	3000	180.0	180.0	18.0
INA199B2DCKT	SC70	DCK	6	250	180.0	180.0	18.0
INA199B2DCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA199B2RSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA199B3DCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA199B3DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA199B3DCKT	SC70	DCK	6	250	180.0	180.0	18.0
INA199B3DCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA199B3RSWR	UQFN	RSW	10	3000	200.0	183.0	25.0
INA199B3RSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA199B3RSWRG4	UQFN	RSW	10	3000	210.0	185.0	35.0
INA199C1DCKR	SC70	DCK	6	3000	340.0	340.0	38.0
INA199C1DCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA199C1RSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA199C1RSWRG4	UQFN	RSW	10	3000	210.0	185.0	35.0
INA199C2DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA199C2DCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA199C2RSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA199C3DCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA199C3DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA199C3DCKT	SC70	DCK	6	250	180.0	180.0	18.0
INA199C3DCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA199C3RSWR	UQFN	RSW	10	3000	210.0	185.0	35.0

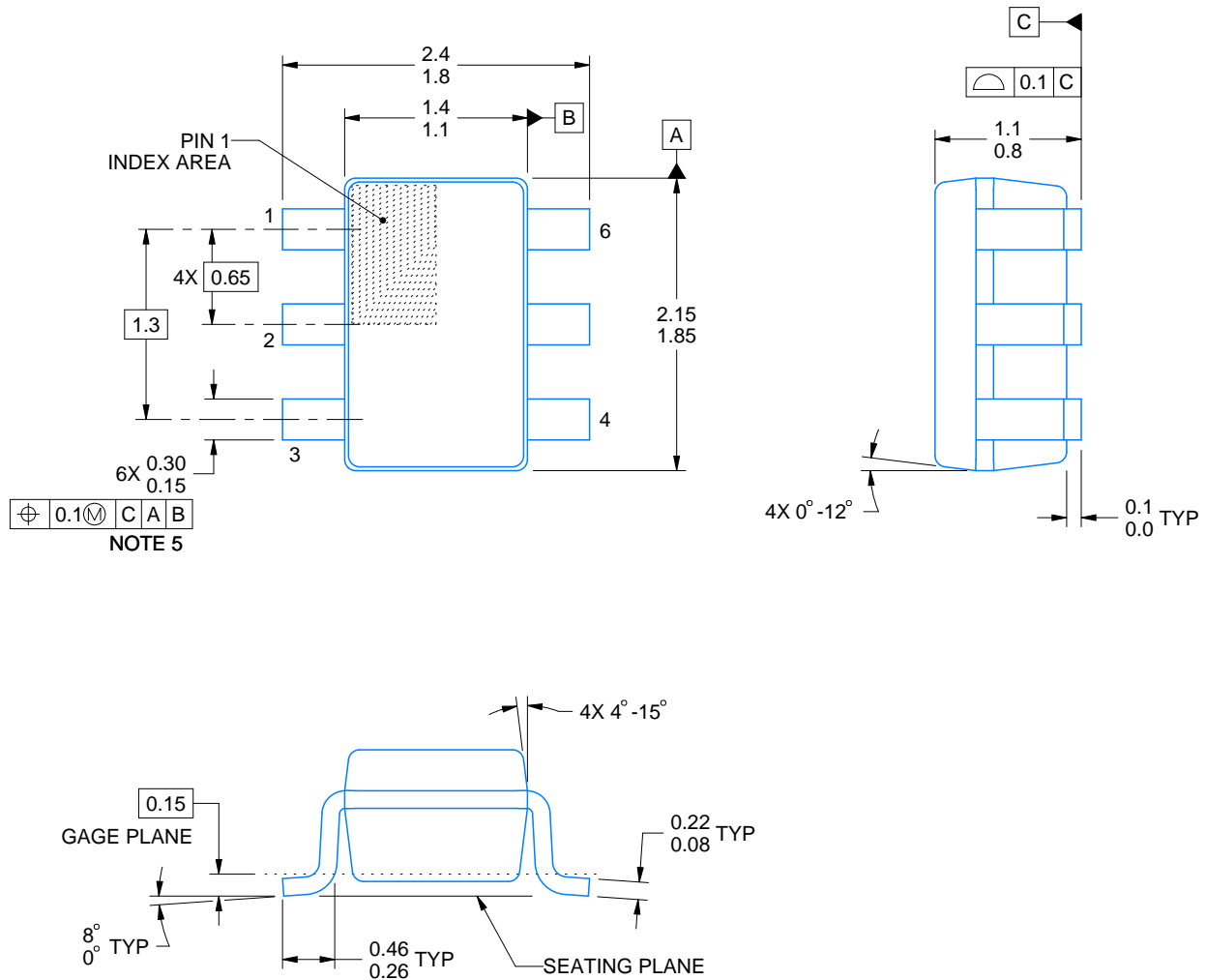
DCK0006A



PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



4214835/D 11/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
4. Falls within JEDEC MO-203 variation AB.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X

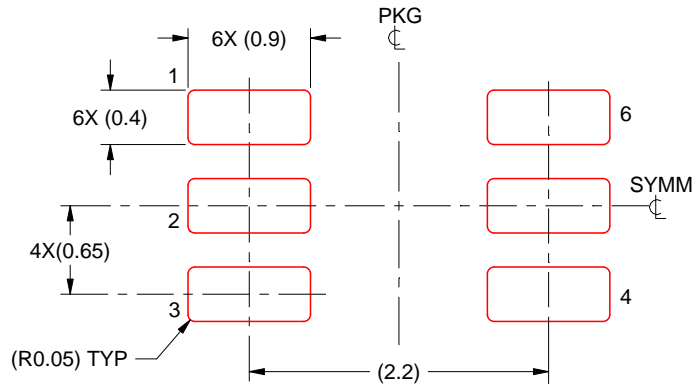


SOLDER MASK DETAILS

4214835/D 11/2024

NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
 BASED ON 0.125 THICK STENCIL
 SCALE:18X

4214835/D 11/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

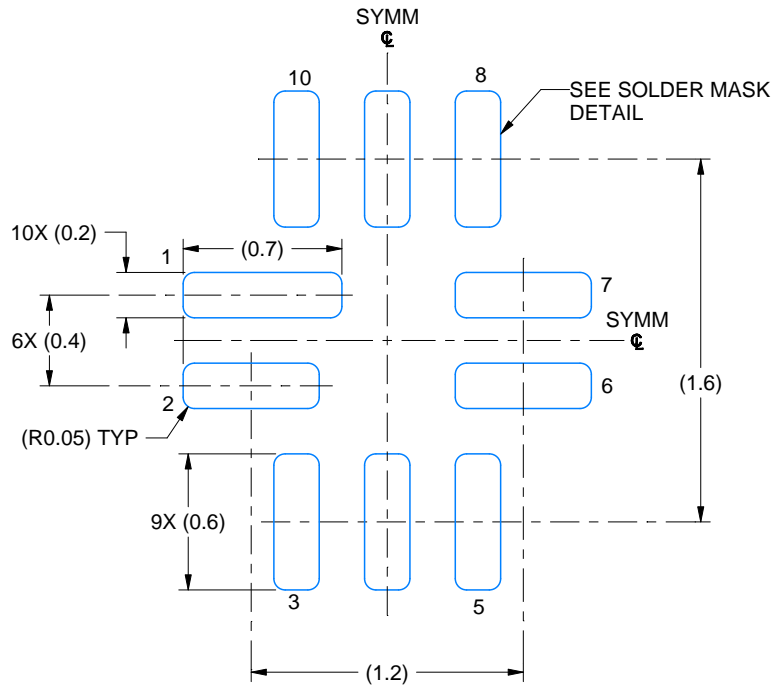
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package complies to JEDEC MO-288 variation UDEE, except minimum package height.

EXAMPLE BOARD LAYOUT

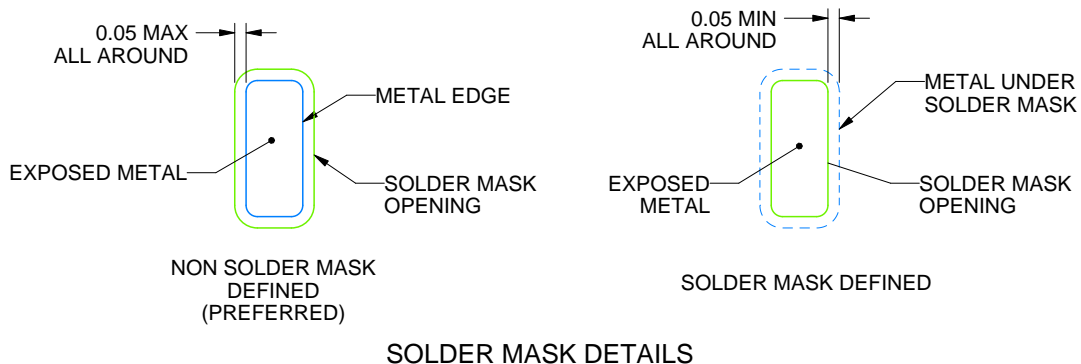
RSW0010A

UQFN - 0.55 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 30X



4224897/A 03/2019

NOTES: (continued)

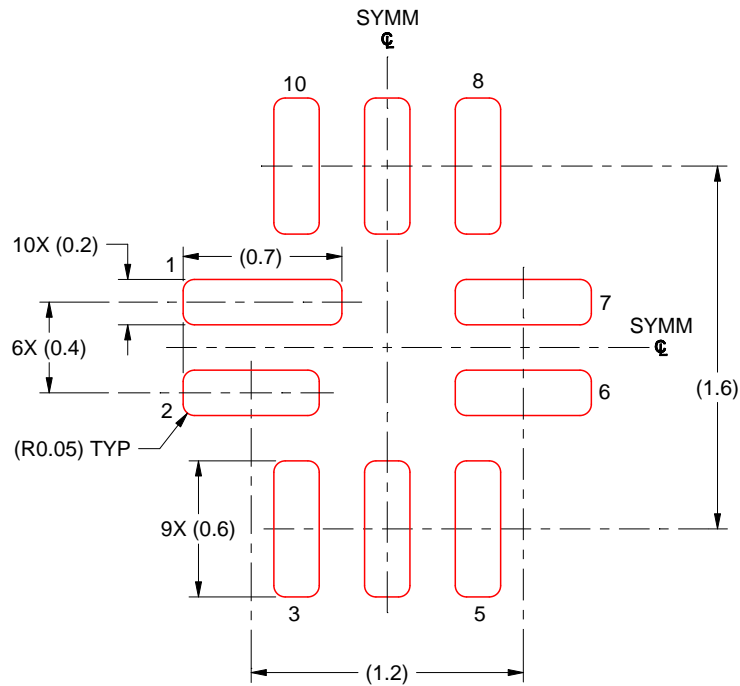
- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RSW0010A

UQFN - 0.55 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 MM THICK STENCIL
SCALE: 30X

4224897/A 03/2019

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](#) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2025, Texas Instruments Incorporated